

Technical Data Data Sheet 257, Rev.-

# SILICON SCHOTTKY RECTIFIER DIE Very Low Forward Voltage Drop (150 °C T<sub>J</sub> Operation)

## **Applications:**

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

#### Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging

# **Maximum Ratings**(1):

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	60	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle, rectangular	30	Α
Current	, ,	wave form		
Max. Peak One Cycle Non-	I <sub>FSM</sub>	8.3 ms, half Sine wave (1)	570	Α
Repetitive Surge Current				
Non-Repetitive Avalanche	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C}, I_{AS} = 1.1  \text{A},$	36	mJ
Energy		L = 60 mH		
Repetitive Avalanche Current	I <sub>AR</sub>	I <sub>AS</sub> decay linearly to 0 in 1 μs	6.0	Α
		f limited by $T_J \max V_A = 1.5 V_R$		
Max. Junction Temperature	TJ	-	-65 to +150	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-65 to +150	°C

### **Electrical Characteristics**(1):

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 30A, Pulse, T <sub>J</sub> = 25 °C	0.56	V
	$V_{F2}$	@ 30A, Pulse, T <sub>J</sub> = 125 °C	0.51	V
Max. Reverse Current	I <sub>R1</sub>	@V <sub>R</sub> = 60V, Pulse,	400	μΑ
		$T_J = 25  ^{\circ}C$		
	$I_{R2}$	@V <sub>R</sub> = 60V, Pulse,	280	mA
		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	$C_{T}$	$@V_R = 5V, T_C = 25  ^{\circ}C$	1600	pF
		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		

(1) in SHD package

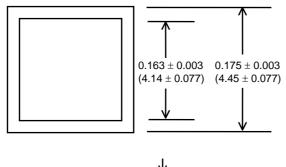
<sup>• 221</sup> West Industry Court ■ Deer Park, NY 11729-4681 ■ (631) 586-7600 FAX (631) 242-9798 •

<sup>•</sup> World Wide Web Site - http://www.sensitron.com • E-Mail Address - sales@sensitron.com •

# SENSITRON SEMICONDUCTOR

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### Mechanical Dimensions: In Inches / mm

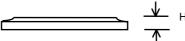


Bottom side metalization Ag - 30 kÅ minimum.

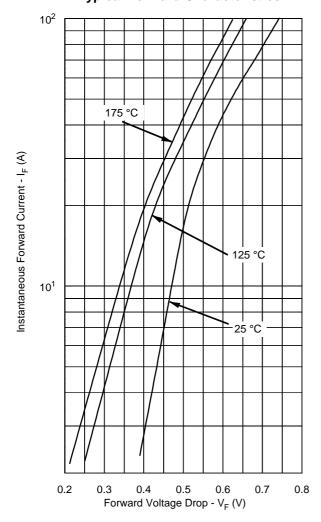
Top side metalization Al - 25 kÅ minimum or Ag - 30 kÅ minimum.

Bottom side is cathode, top side is anode.

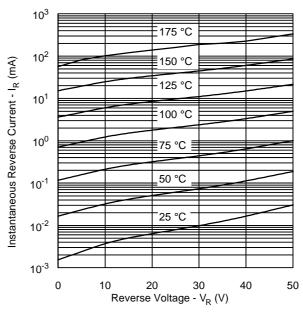
Dimension H = 0.0105  $\pm$  0.001 (0.27  $\pm$  0.026) for Al top; Dimension H = 0.0155  $\pm$  0.001 (0.39  $\pm$  0.026) for Ag top.



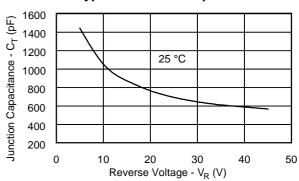
## **Typical Forward Characteristics**



# **Typical Reverse Characteristics**



### **Typical Junction Capacitance**



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